國立交通大學

材料科學與工程學系

博士論文

碳奈米管之高效率離子與化學表面改質製程及其對碳 奈米結構之影響

Study on highly efficient ion and chemical surface modification processes and their effects on carbon nanostructures **TITLES**

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中 華 民 國 九 十 八 年 六 月

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碳奈米管之高效率離子與化學表面改質製程及其對碳奈米

結構之影響

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摘 要

為了提高碳奈米管(CNTs)應用之可能性,本研究主要目的為針對不同多壁碳奈米 (MWCNTs)之表面改質技術進行研究,同時檢視其對碳奈米結構之影響。此製程包括利 用提供不同氫/氧混合比例之氣體進行離子處理以及/或是使用兩種不同酸溶液進行酸 處理。此實驗之離子乃藉由發散磁場以及施加於電漿區下 28 cm 處之樣品台偏壓自電漿 萃取出,而此電漿由電子迴旋共振微波化學氣相沉積系統(ECR-MPCVD)所產生。而酸 處理則使用 0.25 M 之稀釋硝酸溶液以及濃硝酸與濃硫酸之混合溶液(HNO3:H2SO4 = 1:3 (v/v)),同時以不同的超音波震盪時間進行酸處理。經過處理後之碳奈米管,則藉由 X 射線光電子能譜儀(XPS),掃瞄式電子顯微技術(SEM),穿透式電子顯微技術(TEM),拉 曼光譜技術(Raman spectroscopy),以及熱重分析法(TGA)進行結構及性質分析。

理想碳奈米管之官能基化本質上為藉由鍵結含氧官能基於碳管表面以便改變表面 性質,而對奈米結構無太大之破壞。表面處理可能包括非結晶碳之消除、結構缺陷之形 成或破壞。酸處理之效應,基本上藉由氧化碳管表面以產生自由基鍵並且稼接官能基於 此鍵上,比較以濃硝/硫酸與稀釋硝酸處理之碳奈米管官能基化程度與結構之破壞,結 果顯示以強酸進行酸處理,可使碳奈米管具較高的官能基化程度(高[O]/[C]值,最高可 至 52.7%),但結構破壞過大(較高的 I_D/I_G 值至 0.96 以及較低的熱分解溫度至 638 °C), 由於 XPS 及 Raman 探測媒介的穿透深度限制,所量測之 $[O]/[C] \cdot sp^2 \cup \mathcal{R}$ I_D/I_G 值,僅 代表接近碳奈米管表面之量測結果。此外,傳統之酸處理亦具有汙染及處理時間過長(將 近 9 小時)之缺點。

離子處理之效應本質上藉由使用高負偏壓值以便以較多陽離子轟擊碳奈米管並於 碳管表面形成較多自由基鍵。同時,萃取自電漿具高還原電位之氧陽離子則易於此自由 基鍵上鍵結而將碳管表面官能基化。實驗結果顯示,經離子處理後之碳奈米管,其 $[{\rm O}]/[{\rm C}] \cdot {\rm sp}^2$ 值對於氫/氧氣體流量比之曲線具有最大值而 ${\rm I_D/I_G}$ 具有最小值。最大官能基 化程度之產生端賴於碳管表面之自由基鍵形成與萃取自電漿之氧化陽離子含量兩者間 的競合關係。總言之,本研究之離子處理對於碳奈米管結構並無明顯之破壞,同時在中

間的氫/氧氣體流量比(= 25/25 (sccm/sccm))下,當離子處理時間為 5 分鐘及 20 分鐘時, 官能基化程度之[O]/[C]值分別可達 31.1%及 59.8%.

而利用結合 5 分鐘之離子前處理與稀釋硝酸處理之兩階段製程來處理碳奈米管,結 果顯示出,在中間的氫/氧氣體流量比(=25/25(sccm/sccm))下,經離子處理之碳奈米 管,再經過稀釋硝酸處理兩小時後,由於可提高碳管提高管徑分布之尺寸,故可將碳奈 米管之分解溫度自~ 595 ℃ 提高到至 684 ℃,同時不會犧牲其官能基化之結果([O]/[C] =52.4%)。比較不同的製程方法,在不使用離子處理下,濃硝/硫酸與稀釋硝酸製程處理 皆可藉由減小雜質與減小心管徑之碳奈米管以提高管徑分布之尺寸來達到提升碳奈米 管之分解溫度,但會造成碳奈米管之結構破壞過大或是製程時間過長的問題。總言之, 結合離子前處理與稀釋硝酸後處理乃為一簡單且有效之官能基化方法,同時在不產生過 大之結構破壞下提高碳奈米管之分解溫度。

Study on highly efficient ion and chemical surface modification

processes and their effects on carbon nanostructures

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Abstract

For extending the potential applications of carbon nanotubes (CNTs), various processes to modify the surface of the multi-walled carbon nanotubes (MWCNTs) were studied, and effects on carbon nanostructure were examined. The processes included the ion treatment by using various flow ratios of H_2/O_2 gas mixtures and/or acid treatment of two different compositions. The ions for treatment were extracted from the plasma, generated by an electron cyclotron resonance assisted microwave plasma chemical vapor deposition (ECR-MPCVD) system, through the divergent magnetic flux and the bias voltage application on the specimen stage at the position 28 cm below the plasma zone. The solutions for acid treatment included 0.25 M nitric acid or nitric/sulfuric $(HNO_3:H_2SO_4=1:3 \ (v/v))$ acids. The acid treatments were conducted under various sonication times. The MWCNTs after each processing step were characterized by X -ray photoelectron spectroscopy (XPS), scanning electron microscopy (SEM), transmission electron microscopy (TEM), Raman spectroscopy, and thermogravimetric analysis (TGA).

Optimum functionalization of CNTs is essentially to bond more oxygen-containing functional groups on the surface to vary their surface properties without too much damage to the nanostructures. The surface treatment may include amorphous carbon elimination, structure defect formation or damage. Effect of acid treatment is basically to oxidize the surface of the nanotubes to create free radical bonds and to graft polar functional groups to the free bonds. By comparing the degree of functionalization and structure damage of CNTs of nitric/sulfuric acid with the dilute nitric acid treatments, the results show that former treatment results in a greater functionalization (i.e. higher [O]/[C] values, up to 52.7%) but too much structure damage (i.e. higher I_D/I_G ratios and lower decomposition temperatures, up to 0.96 and down to 638 °C), though the values of [O]/[C], sp^2 and I_D/I_G merely represent the near surface features due to limitation of penetration depth of XPS and Raman probes. Other drawbacks of the traditional acid treatment are its pollution issue and too long treating time (up to 9 h).

Effect of the ion treatment by using high negative substrate bias (-250 V) is essentially to bombard CNTs by more positive ions and create more free radical bonds on their surface. Meanwhile, the oxygen cations extracted from plasma can readily be bonded with these free radical bonds to functionalize the surface. The results indicate that there are existence of maximum values of [O]/[C] and sp², and minimum values of I_D/I_G values at medium H_2/O_2 ratios. The existence of maximum functionalization is due to the competition between the amount of free radical bonds on nanotube surface and oxygen cations in the plasma stream. In summary, at medium H_2/O_2 ratio (= 25/25 (sccm/sccm)), the ion treatment in the present cases causes no significant structure damage, and at treatment times of 5 and 20 minutes, the [O]/[C] values of the functionalization degree, are 31.1% and 59.8% , respectively.

For process combining the 5 min ion pretreatment and a post dilute nitric acid treatment, the results show that the ion-treated MWCNTs at medium H_2/O_2 ratio (= 25/25 (sccm/sccm)) can be further treated by the dilute acid to increase the decomposition temperature from \sim 595 ^oC up to 684 ^oC without sacrificing the functionalization ([O]/[C] =52.4%) owing to the increase of size distribution change of the nanotube. By comparing different process methods, both nitric/sulfuric and dilute nitric acid treatment, without the ion treatment can also enhance decomposition temperature by eliminating the impurities and the smaller CNTs to vary the size distribution of the tubes but it causes either too much structure damage or too long treating time. In summary, the process with the ion pretreatment and followed by a dilute acid treatment is relative simple and efficient to functionalize CNTs, simultaneously enhance the decomposition temperature and cause no significant structure damage.

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Chapter 1

Introduction

A single-walled carbon nanotube (SWCNT) can be described as a layer of hexagonal graphene sheet rolled into a seamless cylinder whilst a multi-walled carbon nanotube (MWCNT) is formed with multiple graphene layers. This results in a nanostructure with high aspect ratio (length-to-diameter) exceeding up to $100,000$ ^[Saito 2004-p35]. Such cylindrical carbon molecules have novel [properties](http://en.wikipedia.org/wiki/Chemical_property) that make them potentially useful in many applications, such as biosensors, drug and vaccine delivery vehicles, protein transporters, artificial muscles, novel biomaterials, and solar power [Venkatesan 2005- 7154, Bianco 2005-674, Smart $2006-1034$, Chiu $2008-3024$, Landi $2005-165$. To date, in order to fulfill many application requirements, variety methods have also been proposed for the synthesis of CNTs, e.g. arc discharge [Saito ^{1995-979]}, laser ablation $\frac{[\text{Guo 1995-49}]}{[\text{Guo 1995-49}]}$ and chemical vapor deposition (CVD) $\frac{[\text{Lee 2001-245}]}{[\text{Leg 2001-245}]}$.

As mentioned by previous study, the resulting products often contain unwanted carbon impurities such as nanocrystalline graphite and fullerene [Landi 2005-9952]. In addition, the inactive layer formed by amorphous carbon on the outer surface has been suggested as the main cause of bundling [Felten 2005-074308-1, Ionescu 2006-36]. Because most applications of CNTs involve their dispersion in polymer or aqueous matrices, the agglomeration of CNTs can significantly reduce their usefulness $[Fu \ 2003-351, Liu \ 1998-1253]$. Therefore, post-synthesis treatments are often called for in order to remove the byproducts or graft covalent bonding on their sidewall without damaging the CNTs structure. To date, many researchers are resorting to the use of strong acids that can have a serious impact on the integrity of nanotubes. Acid treatment is based on selective oxidation to remove amorphous carbon through sonicating or refluxing the nanotubes in a strong acid. It is found to effectively remove metals from the reaction products [Tohji 1996-679, Hou 2002-81, Park 2001-655] and introduce oxygenated groups such as carboxylic acids $(-COOH)$, carbonyls $(-C=O)$, and hydroxyls $(-OH)$ on the surface of the nanotubes. This enhances the polarity of the nanotubes which is an advantageous property $[Fu]$ 2003-351, Ovejero 2006-2206, Dujardin 1998-1472, Li 2003-858, Park 2006-141]. However, the drawbacks of this method include degradation of the length of the CNTs and oxidative damage to the nanotubes [Fu 2003-351, Ovejero 2006-2206, Dujardin 1998-1472, Li 2003-858, Park 2006-141] .

Recent studies have shown that plasma treatment can be used to facially modify CNTs and to remove amorphous carbon from the surface of nanotubes [Felten 2005-074308-1, Ionescu 2006-36, Xu 2007-8945, Wu 2007-1336, Khare 2004-8166, Khare 2005-23466, Ahn 2003-2481]. During the treatment, the generated particles and UV light may create free radical bonds on the surface and, additionally, form polar functional groups on the radical bonds [Felten 2005-074308-1]. In addition, the amorphous carbon layer is more active than the cylindrical walls for the formation of volatile products with the oxygen cations which are then removed by the pumping system. Although many results have shown that plasma treatment is effective in facial modification of CNTs, it is also mentioned that the high energy and temperature of the plasma may cause serious structural damage through overheating and over-etching within a short process time [Felten 2005-074308-1, Xu 2007-8945]. Therefore, placing nanotubes away from plasma, and reducing the treatment time and temperature would be the optimal ways to circumvent these issues.

In this study, in order to find a method to efficiently functionalize CNTs with insignificant structure damage and to extend the potential applications of carbon nanotubes (CNTs), various processes to modify the surface of the multi-walled carbon nanotubes (MWCNTs) were studied, and effects on their nanostructure were examined. The processes included the ion treatment of various flow ratios of $H₂/O₂$ gas mixtures and/or acid treatment of two different compositions. The ions for treatment were extracted from the plasma, generated by an electron cyclotron resonance assisted microwave plasma chemical vapor

deposition (ECR-MPCVD) system, through the divergent magnetic flux and the bias voltage application on the specimen stage at the position 28 cm below the plasma zone. The solutions for acid treatment included 0.25 M nitric acid or nitric/sulfuric $(HNO₃:H₂SO₄=1:3$ (v/v)) acids. The acid treatments were conducted under various sonication times. The MWCNTs after each processing step were characterized by X-ray photoelectron spectroscopy (XPS), scanning electron microscopy (SEM), transmission electron microscopy (TEM), Raman spectroscopy, and thermogravimetric analysis (TGA).

Chapter 2

Literature review

2.1 Structures and properties of CNTs

CNTs are one of the most exciting new materials for the past decades in the field of nanoscience and nanotechnology. CNTs are giant fullerenes which, by definition, is a closed convex cage molecule containing only hexagonal and pentagonal faces [Pillai 2007-3011]. Formed from essentially the graphite sheets (or graphene sheets), CNTs normally exists with varied structures, differed in length, type of chirality, and number of layers [Saito 2004-p35, Pillai 2007-3011] .

(a) (b) (c)

Theoretically, a single-walled carbon nanotube (SWCNT) can be described as a layer of hexagonal graphene sheet rolled into a seamless cylinder whilst a multi-walled carbon nanotube (MWCNT) is formed with multiple graphene layers $^{[Saito 2004-p35]}$. This leads to different types of structural arrangements, which are typically classified as non-chiral and chiral structural types, due to different rolling direction ^[Saito 2004-p35]. In non-chiral structures of SWCNTs, the honey comb lattices of the nanotube are parallel to the tube axis and these are known as armchair (Fig. 2.1(b)) and zigzag (Fig. 2.1(c)) arrangements $^{[Saito 1992-2204]}$. In armchair structure, two C-C bonds on opposite sides of each hexagonal lattice are perpendicular to nanotube axis; in zigzag structure, the bonds are parallel to nanotube axis. Different from non-chiral structures, the C-C bonds in chiral structures (Fig. 2.1(a)) are with an angle to nanotube axis.

the translation vector **T**. [Dresselhaus 2005-47]

As shown in Fig. 2.2, when sites O and A , and B and B' are connected, respectively, a portion of a graphene sheet can thus be rolled seamlessly to form a SWCNT. Meanwhile, vectors OA and OB are defined as the chiral vector, **Ch**, and the translational vector **T** of the nanotube, respectively [Saito 2004-p38]. This rectangle portion, OAB'B, is then defined as a unit cell for the nanotube. Generally, a SWCNT is mathematically specified by a chiral vector, C_h , (Fig. 2.2(a)) and the C_h is given by ^[Dresselhaus 2005-47, Saito 2004-p46]

$$
C_h = na_1 + ma_2 \equiv (n, m) \tag{1}
$$

where a_1 and a_2 are unit vectors in two-dimensional (2D) hexagonal lattice and n and m are integers. Meanwhile, chiral vector is often described by a pair of indices (n, m). With chiral vector, $C_h = (n, m) = (4, 2)$, the nanotube in figure Fig. 2.2 is described as a $(4, 2)$ nanotube. A chiral angle, θ , is defined as the angle between C_h and a_1 and given by ^[Dresselhaus 2005-47]

$$
\theta = \tan^{-1}\left(\frac{\sqrt{3}m}{2n+m}\right) \tag{2}
$$

When a graphene sheet is rolled into a nanotube, the C_h (or vector OA) forms the circumference of the circular cross-section of the nanotube with the ends of the vector superimposing with each other. Different pairs of integers (n, m) define a different rolling way to form a nanotube. This means the chiral vector determines the rolling direction of a graphene sheet to form a nanotube. Note that a lattice point (n, m) is superimposed with an origin $(0, 0)$. In this sense, a diameter, d_t , of the nanotube can be expressed as ^{[Dresselhaus 2005-47,}] Saito 2004-p46]

これを製薬された。

$$
d_t = \frac{|C_h|}{\pi} = \frac{\sqrt{3}a_c - c\sqrt{n^2 + nm + m^2}}{\pi \ln \left(\frac{m}{n} \right)^{1/2}}
$$
(3)

where $a_{c-c} = 1.44$ Å is the nearest neighbor $C-C$ distance in the graphene sheet $\frac{[Saito 2004-p46]}{[Saito 2004-p46]}$. When n = m and $\theta = 30^{\circ}$, armchair nanotubes are obtained while zigzag nanotubes correspond to either n or m are equal to 0 and $θ = 0$. In addition, all other nanotubes have θ values ranging from 0 to 30° .

Fig. 2-3 (a) The unit cell, (b) the Brillouin zone of a graphene, and (c) the cutting lines for (4,2) nanotube [Dresselhaus 2005- 47]

As shown in Fig. 2.3(a) a unit cell is plotted as a dotted rhombus in real space with

containing the sites A and B, where carbon atoms are located $[Dresselhaus 2005-47]$. Fig. 2.3 (b) reveals the Brillouin zone, i.e. the shaded hexagon, in reciprocal space of the 2D graphite layer. Meanwhile, a_i and b_i , where $i = 1$ and 2, in the figure are the basis vectors and reciprocal lattice vectors, respectively. It is shown that the direction of the reciprocal vectors, **and** $**b**₂$ **, of the reciprocal hexagonal lattice are rotated by 30** \circ **from the basis vectors, a₁ and** a2, of the hexagonal lattice in real space. Three high symmetry points, *Τ, K* and *M* are also indicated in Fig. 2.3 (b) $^{[Dresselhaus 2005-47]}$. As shown in Fig. 2.3 (c), some parallel cutting lines are plotted in circumferential direction and labeled by the cutting line index μ , which assumes the integer values from $1 - \frac{N}{2}$ $\frac{N}{2}$ = -13 to $\frac{N}{2}$ = 14 ^[Dresselhaus 2005-47]. Each of the discrete values of the circumferential wave vectors, one-dimensional (1D) energy bands will appear (one π -band and one π^* -band)^[Saito 2004-P47].

From the theoretical viewpoint, carbon nanotubes are interesting as a 1D periodic graphene structure along the tube a xis $[^{Saito-1992-2204]}$. The confinement in the radial direction can be induced by the 1D monolayer nanotube [Saito 1992-2204]. In order to define a unit cell for the 1D nanotube, the vector OB in Fig. $2.2(a)$ is defined as the shortest repeat distance along the nanotube axis [Dresselhaus 2005-47] .

The translation vector T is then defined as $^{[Dresselhaus\ 2005-47, Saito\ 2004-p46]}$

$$
T = t_1 a_1 + t_2 a_2 \equiv (t_1, t_2)
$$
 (4)

where t_1 and t_2 are given by

$$
t_1 = \frac{2m+n}{d_R}, \ t_2 = -\frac{2n+m}{d_R} \tag{5}
$$

where the greatest common divisor, d_R , of (2m+n, 2n+m) is given by

$$
d_R = \begin{cases} d, \text{ when } n - m \text{ is not a multiple of 3d} \\ 3d, \text{ when } n - m \text{ is a multiple of 3d} \end{cases}
$$
 (6)

Both translation vector, \mathbf{T} , and chiral vector, C_h , determine the unit cell of the carbon nanotube in real space. The reciprocal lattice vectors \mathbf{K}_2 along the nanotube axis and \mathbf{K}_1 in the circumferential direction are the corresponding vectors in reciprocal space and K_1 vetcor gives the discrete *k* values in the direction of the chiral vector C_h ^{[Dresselhaus 2005-47]. The vectors K_1} and **K**₂ can be obtained from the relation $\mathbf{R}_i \cdot \mathbf{K}_j = 2\pi \delta_{ij}$, where \mathbf{R}_i and \mathbf{K}_j are the lattice vectors in real and reciprocal space and should follow the relations [Dresselhaus 2005-47]

$$
\mathbf{C}_h \cdot \mathbf{K}_1 = 2\pi, \mathbf{T} \cdot \mathbf{K}_1 = 0, \mathbf{C}_h \cdot \mathbf{K}_2 = 0, \mathbf{T} \cdot \mathbf{K}_2 = 2\pi
$$
 (7)

From Eq. (7), \mathbf{K}_1 and \mathbf{K}_2 can be written as

$$
\begin{cases}\nK_1 = \frac{1}{N}(-t_2b_1 + t_1b_2) \cdot S \\
K_2 = \frac{1}{N}(mb_1 - nb_2)\n\end{cases}
$$
\n(8)

The N wave vectors μ K₁ (μ =1-N/2, …, N/2) may lead to N discret k vectors or cutting lines as mentioned previously $^{[Saito 2004-P47]}$. For a particular (n, m) nanotube, when a cutting line passes through a K point in the 2D Brillouin zone, where the π and π^* energy bands of 2D graphite are degenerate by symmetry, the 1D energy bands will be with a zero energy gap and show a metallic behavior [Saito 2004-P60]. On the other hand, it is expected to show semiconducting behaviors if no cutting line passes through the point $^{[Saito\ 2004-P60]}$. Owing to the translation symmetry of T, there are continuous wave vectors in the direction of K_2 for CNT with infinite length ^[Saito 2004-P47]. However, when a nanotube is with finite length of L, the spacing between discrete wave vectors along the tube axis is thus $2\pi/L$ [Saito 2004-P47].

Considering the tube geometry, some mixing of the π (2p_z) and σ (2s and 2p_{x, y}) carbon orbitals may appear owing to the tube curvature [Saito 1992-2204]. However, the mixing is

marginal near the Fermi level and, therefore, only π orbitals are required to be considered [Saito] ^{1992-2204]}. Therefore, the 2D energy dispersion relations for π bands of graphene layer can be obtained by the equation [Saito 2004-P62]

$$
E_{2D} = \pm \gamma_0 \left[1 + 4 \cos \left(\frac{\sqrt{3} k_x a_{c-c}}{2} \right) \cos \left(\frac{k_y a_{c-c}}{2} \right) + 4 \cos^2 \left(\frac{k_y a_{c-c}}{2} \right) \right]^{\frac{1}{2}}
$$
(9)

where γ_0 is the nearest-neighbor overlap integral $\left[$ Jishi 1994-2252] and a_{c-c} is a lattice constant as mentioned previously. When k_x or k_y are eliminated by using the periodic boundary condition^[Saito 1992-2204],

$$
C_h \cdot k = 2\pi q \tag{10}
$$

where q is an integer, 1D energy bands can be thus obtained for general chiral structures through slicing the 2D energy dispersion relations of Eq. (9) in the directions expressed by Eq. (10) ^[Saito 1992-2204].

Fig. 2-4 Electronic density of states for two (n, m) zigzag nanotubes: (a) (9, 0) and (b) (10, 0) [Saito 1992-2204]

As shown in Fig. 2.4, the density of states for two zigzag nanotubes with $(n, m) = (10, 0)$ and (9, 0) are plotted according to the units of states per unit cell of 2D graphite. For comparison purpose, the corresponding density of states of 2D graphite is also plotted with dotted lines. Meanwhile, the $1/\sqrt{E}$ singularities of 1D energy bands can be observed at the band edges of each energy band $^{[Saito 1992-2204]}$. As shown in Fig. 2.4 (a), it is also observed that there is an energy gap at the Fermi level, where $E = 0$, while there is a finite density of states in Fig. 2.4 (b), and semiconducting (Fig. 2.4(a)) and metallic (Fig. 2.4(b)) nanotube are thus present. Normally, to determine a nanotube as a metallic type should follow the condition ^{[Saito}] 1992-2204]

$$
2n + m = 3b \tag{11}
$$

where b in an integer. This condition can be obtained by substituting the k vector of the degenerate point of 2D graphite at the corner of the Brillouin zone into Eq. (10). Normally, the chiral vectors are only located in the range, $-30^{\circ} < \theta < 0^{\circ}$, as shown in Fig. 2.2 ^{[Saito}] ^{1992-2204]}. It is suggested that all armchair nanotubes and zigzag nanotubes should be metallic when n is a multiple of three $\frac{[S_{\text{aito}}\ 1992-2204]}{[S_{\text{aito}}\ 1992-2204]}$

Interestingly, it is proposed that if the distribution of C_h vectors shown in Fig. 2.2 is uniform, $1/3$ of the nanotubes will be with metallic behaviors and $2/3$ of those will be with semiconducting behaviors [Saito 1992-2204]. However, a larger fraction of metallic CNTs may be obtained if the initial seed of the tube caps is centered on a pentagon. This leads to an armchair nanotube [Saito 1992-2204]. On the other hand, if the initial seed is a hexagon other than a pentagon, the nanotube might be grown with a planar graphite structure [Saito 1992-2204]. Based on this point, it is suggested that nature might prefer armchair-type nanotubes ^[Saito 1992-2204].

2.2 Synthetic methods of CNTs

Until recently, many methods have been developed to synthesize CNTs in three primary approaches including arc-discharge, laser ablation and chemical vapor deposition (CVD) $[Lee]$ 2001-245; Pillai 2007-3011]. In these methods, carbon sources are normally provided in gas or solid states. Meanwhile, the morphology and properties of CNTs are often controlled with the process parameters including substrate temperature, precursor gases and gas ratio, catalyst, pretreatment conditions, and bias voltage, etc. However, the proposed methods still suffer from the problems, such as low yielding and low uniformities in structure and property.

2.2.1 Arc-discharge method

CNTs were first synthesized by arc-discharge method and identified by Iijima [Iijima 1991-56]. As shown in Figure 2.5 $^{[Saito 1995-979]}$, two graphitic rods are used as anode and cathode in this arc-discharge system. In the process, arcing occurs when DC voltage is applied between these two electrodes. With containing small amount of catalysts, such as Fe, Co, Ni, and Y, the SWCNTs can be synthesized at the anode [Bethune 1993-605] whilst MWNTs can be fabricated using pure graphite as two electrodes.

Fig. 2-5 Schematic of arc-discharge system [Saito-1995-3062]

The discharge system is normally operated with voltages ranging from 20 to 40 V and current from 40 to 100 A under He or Ar gas pressure of $10 \sim 500$ Torr. Carbon clusters, collided out from the anodic graphite rod through electron bombardment, are deposited on the cathode surface. The products on the cathode may include amorphous carbon, fullerenes, carbon cluster, carbon nanotubes, and other carbon structures. Therefore, post treatment to purify the nanostructures is often required for practical uses. Another drawback is its low

yielding in producing CNTs.

2.2.2 Laser ablation

Laser ablation was first reported by Guo's group in 1995 $[Guo 1995-49]$, as shown in Fig. 2.6. An incident laser beam is used to vaporize graphite target under helium or argon gas atmosphere with pressure of 500 Torr. The products are swept out by the flowing gas and to be deposited on the water cooled collector. Therefore, it is also named as laser vaporization method. Normally, the graphite target used in this method often containing Co, Ni, Fe, or Y and this is a favorable condition of forming SWCNTs.

2.2.3 Chemical vapor deposition

As shown in Fig. 2.7, thermal chemical vapor deposition $[Lee^{2001-245}]$ applies the pyrolysis of hydrocarbon source to synthesize the CNTs. This method is also a catalyst-assisted SWCNTs growth method and is one of the most commonly used methods. Meanwhile it is considered the best solution for nanoscale device fabrication because it not only allows a scalable process but also enables selective growth on patterned catalyst film $^{[Golovko 2005-1636]}$. The formation of CNTs using CVD involves the formation of small catalyst nanoparticles, decomposition of hydrocarbon gases such as CH_4 and C_2H_2 , and then growth of the nanotubes on the metal catalysts. Normally, the catalyst particles are coated on substrate and reduced by CVD using hydrogen plasma to form well-distributed and active metallic nanoparticles. Nanosized catalytically metal particles are formed after the catalytic metal film is etched with NH₃ gas at a temperature ranging from 750 to 1050°C. Reaction gas is supplied from one end of the apparatus and evacuated from the outlet on the other side. The merit of this method is capable of depositing large area, and uniform as well as good quality of SWNTs. However the drawback of this method is not compatible with IC (integrated circuit) process due to the high working temperature over 600 °C.

PECVD system is the most employed method for depositing CNTs $^{[Qin 1998-3437]}$ compared with the other methods because this method can be compatible to IC process for its low process temperature and a cheap, less contamination, and high yielding process. Meanwhile, this process is highly capable of producing controlled alignment of SWCNTs. Therefore, many new techniques have been developed to prepare vertically aligned SWCNTs through using this method.

In practical uses, the plasma is activated by a microwave plasma apparatus using RF or DC discharged system, microwave plasma assisted hot filament, and electron cyclotron resonance (ECR) plasma source. In general, the typical power supplies used in this method are DC bias, radio frequency (RF) (13.56 MHz) and microwave (2.45 GHz). During the process, SWCNTs are produced by the decomposition of hydrocarbon (such as CH_4 , C_2H_2 , C_2H_4 and C_6H_6) or monoxide, and then deposition on nanoparticles of transition-metal.

Fig. 2-9 Schematic of PE-HF-CVD apparatus^[Kurt 2001-1723]

As shown in Fig. 2.8, with the high density of plasma, the MP-CVD system ^[Qin 1998-3437] is a contamination-free process and the plasma shape can be regulated through adjusting the cavity. The PE-HF-CVD system applies the current of the tungsten filament to efficiently increase the temperature in the process chamber $\frac{Kurt 2001-1723]}{s}$ as depicted in Fig. 2.9. As shown in Fig. 2.10, ECR-CVD system is well known for its advantages of high dissociation percentage of the precursor gas, high uniformity of plasma energy distribution and large area of CNTs deposition [Tsai 2001-NCTU].

2.3 The proposed growth mechanisms of catalyst-assisted CVD

In order to well control the synthesizing process of CNTs, it is very important to understand of the growth mechanism of CNTs. Until recently, although many detailed and precise growth have been proposed, most of them are still in controversy $[K_{UQ} 2004-p9-2]$. However, it is believed that the application of catalyst is required to synthesize CNTs in diameter ranging from 0.7 to 2 nm for the growth process $\frac{K_{UQ}^{2004-p9-9}}{201}$. It is also known that the application of alloy catalyst can increase the growth quantity of SWCNTs significantly. Some of the growth mechanisms of SWCNTs are demonstrated as blew:

(a) Root growth model

Proposed by Saito et al., this model is used to explain the growth mechanism of radiate sea-urchin-like SWCNTs by using arc-discharge $[^{Saito}]$ $[^{Saito}]$ $[^{Salto}]$ In their study, numerous SWCNTs grow from single catalyst particles and their resulting diameters are much smaller than the particles. It is proposed that carbon-metal alloy can be formed by vaporization during arc discharge process; this alloy posses higher carbon solubility than in a solid state. Therefore, the liquid alloy particles tend to segregate excess carbon on their surface with the decrease of temperature of the cathode.

Two possible occasions can be observed in process. The first is that the cooling rate of the particles proceeds with a moderate rate and the supersaturated carbon in metal particles is not high so that carbon is gradually segregated on the particle surface, forming graphitic layer.

Alternatively, the cooling rate is so rapid that the dissolved carbon in a particle is very high. Supersaturated carbon could cause numerous nucleation sites of graphite on the particle surface. A large number of tiny flakes are thus forming and subsequently closing their open ends in order to saturate dangling bonds at their periphery. SWCNTs can then be formed on the random graphitic flake assembly.

(b) Ball-and-stick catalyst scooting model

This model can be used to explain the phenomenon when catalyst is not found at the tip of SWCNTs ^[Birkett 1997-111]. According to the proposal, transition metals show a high propensity for decoration fullerene surfaces. A carbon fragments bind to the metal clad fullerene and they may self-assemble as a surrounding circular hexagonal chicken-wire-like fence. Once they are formed as a belt, the network could propagate as a cylinder. This is so called open edge growth.

Another similar model, scooter mechanism, considers that a few metal atoms are chemisorbed and scooted around the open edge of the sheet; and this keeps the tube open and grows. SWCNT will stop when the metal atoms aggregate and lose their kinetic energy for **THEFFERE** scooting.

(c) Vapor-liquid-solid growth mechanism

According to this proposed model $[Gorbunov 2002-113]$, a molten catalyst nanoparticle penetrates an amorphous carbon aggregate dissolving it and precipitating carbon atom. These atoms arrange in a graphene sheet whose orientation parallel to the supersaturated metal-carbon melt is not energetically favorable. Any local defect of this graphene sheet will result in its buckling and formation of a SWCNT nucleus. Further precipitating carbons incorporate in edges of growing nanotube, which are anchored to the catalyst nanoparticle by overlapping its unsaturated $sp²$ orbital with the metal orbital of the catalyst nanoparticles.

(d) Yarmulke mechanism

Proposed by Dai et al. $[^{Di 1996-471]}$, this model explains the growth mechanism of CNTs synthesizing on molybdenum nanoparticles by the disproportionate of CO at 1200 ℃ and concludes that catalyst size determines the tube diameter. It is also proposed that tubes are close end and carbon atoms are chemisorbed on the catalyst to for yarmulke first. Subsequently, carbon source decomposes and defuses into catalyst, making SWCNTs longer.

2.4 The proposed surface modification processes of CNTs

Owing to many unique fascinating properties, many recent studies are devoted to employ CNTs for various novel applications such as biosensors, drug and vaccine delivery vehicles, protein transporters, artificial muscles, novel biomaterials, and solar power [Venkatesan 2005- 7154, Bianco 2005-674, Smart 2006-1034, Chiu 2008-3024, Landi 2005-165]. Because most applications of CNTs involve their dispersion in polymer or aqueous matrices, some existing challenges of CNTs can hinder their success. These challenges result from the presence of an amorphous layer on nanotube surface, the nonreactive nature of the CNT surface, the nature of agglomeration of CNTs into bundles, and almost insolubility in any solvent [Felten 2005-074308; Fu 2003-351]. This can significantly reduce their usefulness $[Fu\ 2003-351, Liu\ 1998-1253]$. To overcome this issue, a modification of the CNTs by changing their surface chemical composition has proven to be efficient. Meanwhile, oxygen functionalization can also serve as a purification method for the carbon nanotubes [Lian] $2004-8848$]. Furthermore, functionalizing the CNTs with a number of functional groups is known for increasing their chemical reactivity and can be used as a starting point for further chemical modification ^[Boul 1999-367] for some specific applications.

To date, many functionalization methods, such as electrochemical functionalization ^{[Bahr}] $2001-6542$], fluorination $[An 2002-4235, Mickelson 1998-188]$, Polymer wrapping $[O'connel 2001-265]$, chemical functionalization [Cao 2002-8971, Ago 1999-8116] and plasma treatment, have been developed to improve the solubility and to achieve dispersion of CNTs in water or polymers. Among these techniques, chemical functionalization can be the most common and important way for surface modification of CNTs $^{[Fu\ 2003-351]}$.

2.4.1 Chemical processes

The theory behind modification processes is that the formation of polar functional groups on the surface of CNTs enhances their solubility and dispersion abilities in water or polymers. At present, the chemical method $[Fu^{2003-351}]$ is the most common; in this process, CNTs are normally refluxed or sonicated in a strong acid, such as $HNO₃$ and/or $H₂SO₄$, to produce free radical bonds in $sp²$ structure on nanotube surface and introduce oxygen containing functional groups, such as carboxylic acids $(-COOH)$, carbonyls $(-C=O)$, and hydroxyls $(-OH)$, to the radical bonds [Dumitrescu 2007-12944]. However, the harsh conditions inherent in this method may introduce wall damage, decreasing their stability and even cleaving them into shorter pieces [Harutyunyan 2002-8671, Zhang 2004-149, Dumitrescu 2007-12944]. These processes may also give rise to some unfavorable issues such as waste treatment, as well as time and cost efficiency issues. Treating nanotubes in mild acid may be an alternative to avoid these issues but this results in a very low production efficiency.

2.4.2 Plasma processes

Compared with the chemical processes, plasma treatment has gained lots of attention recently since it is a solvent-free, time efficient, versatile, and environmentally friendly procedure for surface modification [Wu 2007-1336, Khare 2005-23466, Hassanien 2005-278, Zheng 2007-1622]. In addition, this method can provide the greatest opportunity to scale up the production if the system is optimized. Therefore, plasma treatment has been used for a long time in deposition and etching processes in many industrial fields. To date, many approaches have been investigated to demonstrate the viability and performance of plasma treatment for surface modification of CNTs. Among these studies, various gases, such as N_2 ^[Yu 2004-380], H_2 ^{[Zhang}] 2004-54], O₂ [Felten 2005-074308, Ionescu 2006-36, Juan 2005-8231], NH₃ [Zheng 2007-1622, Felten 2005-074308, Ionescu 2006-36],

and CF_4 [Felten 2005-074308, Khare 2004-8166] have been used. Generally, the plasma is generated using glow discharge, radio frequency discharge, or microwave discharge at low-vacuum pressure. The generated ions, radicals, and UV light in plasma interact with the CNT surface, creating free radical bonds on nanotube surface and bonding functional groups to the radical bonds [Felten 2005-074308]. Although plasma treatment has been shown to be effective in facial modification of CNTs, some have mentioned that it may cause serious structural damage due to the high energy and temperature plasma within very short time ^[Felten 2005-074308, Xu 2007-8945]. An alternative that circumvents these issues is placing the nanotubes away from plasma sheath and extracting plasma ions by applying a bias voltage so as to reduce temperature, radiation, and ion density. However, in most designs, plasma sources are working at around 0.1 to 1 Torr pressure which leads to low mean-free-path; this in turn leads to low etching efficiency if the alternative is applied. Active plasma at higher-vacuum pressure may be an optimal solution but this results in a low density plasma that cannot be activated. Therefore, to seek an optimal method with generating high density plasma in high-vacuum is very important.

2.5 The characterization methods

2.5.1 Scanning electron microscopy (SEM)

As shown in Fig. 2-10, after Knoll developed the first Scanning electron microscope (SEM) [Newbury 2000-323], demonstrating most of the basic principles of operation, and a surprisingly modern SEM instrument was subsequently described by Zworykin et al. at RCA [Newbury 2000-323], the SEM has been the most versatile and widely used electron bean instrument in material characterizations $[Joy 1997-465]$ for their abilities to produce high resolution and magnification images. In the research filed of CNTs, SEM has traditionally been an important technique for the characterization of CNTs to monitor the bulk-scale production of CNTs by a variety of synthetic techniques. It is also the most popular tool to evaluate the quality of as-grown CNT soot [Itkis 2005-3439].

Fig. 2-10 SEM purity grading system [Itkis 2005-3439]

On the other hand, some drawbacks can be brought while SEM is used to generate high quality image to evaluate the quality of CNTs [Itkis 2005-3439]. It is mentioned that the metal catalyst contained in nanotube and a thin coating of amorphous carbon on CNTs are invisible to SEM technique but easily observed by Transmission electron microscopy (TEM) technique [Itkis 2005-3439]. Meanwhile, limited by observation scale, more frames with various magnifications is necessary to provide reliable characterization information [Itkis 2005-3439].

2.5.2 Transmission electron microscopy (TEM)

Fig. 2-11 TEM images of (a) SWNTs (b) SWNT bundles (c) DWNT (d) MWNT [Flahaut 2000-249]

TEM technique can reveal the interior microstructure of the specimen, and produce the high-resolution lattice image and the electron diffraction pattern as well. However, in practical use, some drawbacks can be happened. When TEM is used to directly analyze the structure of SWCNT, it is difficult to obtain a clear image of one SWCNT. The main reasons are the structure of SWCNT is easily destroyed by high energy electron beam and electron scattering are not apparent because of SWCNT is composed of so few carbon atoms. Furthermore, SWNT is hard to be built on stilts to avoid the background interference from copper grid and SWNTs dispersion is also an important problem. Figure 2-11 shows the HRTEM images of (a) SWNTs (b) SWNT bundles (c) DWNT (d) MWNT $[Flahaut 2000-249]$. A thin layer of amorphous carbon on nanotube surface may be observed by TEM. However, it is difficult to predict the precise quantity of the layer amount because the TEM energy is so high that the layer structures are easily destroyed and subsequently more amorphous carbon are generated. The
same as SEM technique, with the observation limitation, more frames with various magnifications is often required to provide homogeneous characterization information.

2.5.3 X-ray photoelectron spectrometry (XPS)

Fig. 2-13 XPS C_{1s} spectra of the as-purchased MWCNTs and the five chemical species: (1) graphite; (2) sp^3 carbons; (3) hydroxyl groups; (4) carbonyl groups; and (5) carboxyl groups [Felten 2005-074308]

XPS has its origins in investigations of photoelectric effect in which X-ray is used as the exciting source ^[Briggs 1996-p7]. Based on the equation as below, XPS spectra are obtained by irradiating a material with a beam of X-rays while simultaneously measuring the kinetic energy (E_k) and number of electrons that escape from the surface of material being analyzed.

$$
E_k = h_v - E_B \tag{12}
$$

where h_v is the incident photo energy, and E_B is the electron binding energy. The heart of this technique is the measurement of an electron energy spectrum by using an electron energy analyzer, also called a spectrometer. It is often used to estimate that all aromatic sites at the surface of the oxidized nanotubes [Felten 2005-074308, Ago 1999-8116, Xu 2007-8945, Ionescu 2006-36, Zhang 2007-2366, Wiltner 2004-881] . This technique can also be used to identify chemical composition on material surface and functional groups attached to CNTs. According to the research of Felten et al. ^[Felten 2005-074308], MWCNTs are modified by inductive coupled rf-plasma with applying O₂, $CF₄$ and NH₃ gases and then investigated by XPS to analysis and quantify the chemical composition on nanotube surfaces so as to support their experimental results. Figures 2-12 and 2-13 give their XPS investigation results of the oxygen plasma-treated nanotubes. The XPS survey spectrum in Fig. 2-12 is used to confirm the chemical elements on the surface of nanotubes. The XPS C_{1s} spectrum in Fig. 2-13 is deconvoluted into five Gaussian peaks centered at 284.5, 285.1, 286.2, 287.2, and 288.9 eV after the background are subtracted. The main peak at 284.5 eV originates from the graphite signal The peak at 285.1 eV is attributed to sp^3 carbon atoms. The peaks at 286.2, 287.2, and 288.9 eV correspond to hydroxyl, carbonyl (or ether), and carboxyl (or ester) groups respectively. The XPS results show that after thee nanotubes are treated by the oxygen plasma under various process conditions, the [O]/[C] ratio which is the relative percentage of the oxidized carbon species to total number of carbon species detected is can be increased $[Ago 1999-8116]$.

2.5.4 Raman spectroscopy

Raman spectroscopy provides information about molecular vibrations that can be used for sample identification and quantification. Normally, a monochromatic light (laser) incident on a sample, the photons which make up the light may be absorbed or scattered, or may not interact the material and may pass through it. When [light](http://en.wikipedia.org/wiki/Light) is [scattered](http://en.wikipedia.org/wiki/Scattering) from an [atom](http://en.wikipedia.org/wiki/Atom) or [molecule,](http://en.wikipedia.org/wiki/Molecule) most [photons](http://en.wikipedia.org/wiki/Photons) are elastically scattered [\(Rayleigh scattering\)](http://en.wikipedia.org/wiki/Rayleigh_scattering), such that the scattered photons have almost the same [frequency](http://en.wikipedia.org/wiki/Frequency) as the incident photons. However, a small fraction of the scattered light (approximately 1 in $10^6 - 10^8$ photons) is scattered by an excitation, with the scattered photons having a frequency different from, and usually lower than, the frequency of the incident photons $\frac{[\text{Smith }2005-p2]}{]}$. The energy difference between the monochromatic light and the Raman scattered light is equal to the energy involved in changing the molecule's vibration state $\frac{[\text{Smith }2005-p2]}{[\text{Smith }2005-p2]}$. This energy difference is then called the Raman shift $\frac{[\text{Smith }2005-p2]}{[\text{Smith }2005-p2]}$. Several different Raman shifted signals will often be observed; each being associated with different vibrational or rotational motions of molecules in the sample. Figure 2-14 shows the schematic diagram of state change of Raman scattering $\frac{[Ra_0 1997-187]}{]}$. In CNTs research field, the Raman scattering from SWCNTs is resonantly enhanced if the excitation energy (E_L) matches the separations between the pairs of Van Hove singularities (E_{ii}) in the one-dimensional electronic density of states of the SWCNTs, as shown in Fig. 2-4 ^[Itkis 2005-3439] and Fig. 2-15. It is widely used as a sensitive prober to analysis the electronic structure in carbon nanotubes and presence of defects ^[Dresselhaus 2005-47].

Fig. 2-14 Schematic of state change of Raman scattering [Rao 1997-187]

Fig. 2-15 The left panel shows the electronic transition energies *Eii* vs. nanotube diameter *dt*. The right panels show schematic figures defining the SWNT classes: MOD0 — metallic, where one cutting line crosses the *K* point; MOD1 and MOD2 — semiconducting ^[Dresselhaus 2005-47]

In the inspection of carbon nanostructures, there are two characteristic peaks in Raman spectrum represented as D and G bands. The *D* mode at around 1300 cm⁻¹ is correlated with structural disorder of CNTs, which originates from the defects including disordered materials, poor graphitization, functionalized carbon, and the amorphous carbon on the sidewall of nanotubes [Shaijumon 2007-75, Dillon 2004-691, Jian 2008-230]. The relative intensity of this mode can provide direct evidence of covalent modification and defect concentration. When estimating the defect concentration, the *D* mode intensity is usually normalized with respect to the intensity of the *G* mode at around 1600 cm⁻¹. This approach relies on the assumption that the intensity of the *G* mode is independent of defect concentration and originates from a single resonant Raman process [Jian 2008-230]. On the other hand, if the *G* mode is induced by defects, this procedure for normalizing the intensity is no longer correct [Maultzsch 2002-2647].

The radial breathing mode (RBM) can be used to study nanotube diameter through its frequency (ω_{RBM}) and to perform (n, m) assignment of SWCNTs by analyzing both d_t and I_{RBM} [Dresselhaus 2005-47]. As shown in Fig. 2-16, the RBM of Raman spectrum is a unique feature to SWNTs and involves a collective vibrational movement of the carbon atoms towards and away from the central axis of a SWCNT. It occurs with ω_{RBM} ranging from 120 to 350 cm⁻¹ for diameters, d_t , ranging from 0.7 nm to 2 nm $\left[{\text{Dresselhaus 2005-47}}\right]$. It is therefore very useful for indentifying if a given carbon materials contains SWCNTs.

Fig. 2-16 Raman spectra from a metallic (top) and a semiconducting (bottom) SWNT at the single nanotube [Dresselhaus 2005-47]

RBM frequency for nanotube diameter

The RBM oscillations strongly correlate with a periodicity imposed on a graphene sheet by wrapping it into a finite-size nanotube with small diameter. Consequently, the associated RBM wavelength and frequency are directly related to the perimeter of the nanotube ^{[Dresselhaus}] $2005-47$, as shown in Fig. 2-17. Based on this relationship, as the diameter of the nanotube increases, the RBM frequency decreases to lower wave numbers. On the other hand, for larger

nanotubes and MWCNTs the RBM frequency becomes very small and, at the same time, the intensity of the RBM decreases and ultimately becomes undetectable by Raman spectroscopy measurements. Hence Dresselhaus et al. ^[Dresselhaus 2002-2043] proposed that the frequency of the RBM are:

$$
\omega_{\text{RBM}} = \frac{A}{d_t} + B \tag{13}
$$

where $A = 234$ or 248 cm⁻¹ nm and $B = 10$ or 0 cm⁻¹ for bundle or isolated SWCNTs on silicon wafer, respectively ^[Dresselhaus 2005-47]. Note that, for larger diameter tubes ($d_t > 2$ nm), the intensity of the RBM is very weak and hardly detected. Meanwhile, it should be noted that a single Raman measurement can give an idea of the nanotubes that are resonance with the laser line. However, this cannot give a complete characterization of the diameter distribution of the sample. Alternatively, using many laser lines with different excitation energies can obtain a good characterization of the diameter distribution in the sample.

Fig. 2-17 The Raman vibration modes of CNTs (a) G-band mode (b) D-band mode (c) Radial breath mode [Raravikar 2002-235424]

RBM for nanotube electronic structure [Dresselhaus 2005-47]

SWCNTs can be classified into three different classes, according to whether MOD

 $(2n+m, 3) = 0$, 1, or 2. Here MOD 1 and MOD 2 are two types of semiconducting nanotubes owing to no *k* vector crosses the k point as shown in Figs. 2-3 and 2-15 ^{[Dresselhaus 2005-47]. For} MOD 0, a cutting line crosses the K point. Thus, the SWCNTs are classified as metallic type nanotubes. It is noted that only armchair $(n = m)$ SWCNTs are truly metallic whilst other MOD 0 SWCNTs, i.e., $n \neq m$, are metallic at room temperature but exhibit a small chirality-dependent energy gap at lower temperature ^[Dresselhaus 2005-47]. Fig. 2-15 shows the E_{ii} values for all (n, m) SWCNTs with different diameter ranging from 0.5 to 2.0 nm. Meanwhile, according to Tight-bonding method the E_{ii} values should follow eq. (9) [Kataura 1999-2555]. This results in a so-called Kataura plot and the plot is widely used to interpret the Raman spectra measured from CNTs. Superscript S or M are used to denote whether the electronic transition energies E_{ii}^{M} for metallic SWCNTs else for semiconducting SWCNTs ^[Dresselhaus 2005-47]. The RBM spectra for SWCNT bundle contain an RBM contribution from different SWCNTs in resonance with the excitation laser energy. Therefore, it is useful to probe the electronic data with having a Kataura plot when the RBM spectra from SWCNTs are obtained. It is suggested that, because semiconducting and metallic nanotubes of similar diameters cannot occur at similar Eii values, ω_{RBM} measured from several laser energies E_L can thus be used to characterize the ratio of metallic to semiconducting SWCNTs in the nanotube sample [Dresselhaus 2005-47] .

RBM for chirality assignment [Dresselhaus 2005-47, Jorio 2005-075401]

When the d_t values are obtained from ω_{RBM} under the $E_{ii}-E_L$ resonance conditions, RBM can be used for nanotube chirality (n, m) assignment with the application of Kataura plot. As shown in Fig. 2-16, the spectra are obtained from using a laser excitation energy of E_l = 1.58 eV (wavelength = 785 nm). The observed result for in upper spectrum present in the figure can be assigned as metallic SWCNT (13, 10) with d_t of 1.59 nm, where the E_L is resonance with E_{11}^M . By contrast, the lower spectrum is assigned as (23, 1) SWCNT where E_L

is resonance with E_{33}^S .

As shown in Fig. 2-18(a), some experimental results obtained for E_{ii} vs. ω_{RBM} for each (n, m) resonant nanotube are provided. Meanwhile, in this figure, the E*ii* for nanotubes are clearly seen with the relation of $2n + m = constant$. Meanwhile, as mentioned by Jorio et al. ^{[Jorio} 2005-075401], the Kataura plot should be revised when it is applied on nanotubes in small diameters, as shown in Fig. 2-18b. With the aid of Fig. 2-18(a) and eq. (3), the corresponding values of d_t and $2n+m$ can be obtained. The chiral vector, $C_h = (n, m)$ can thus be calculated.

Fig. 2-18 (a) The revised *Eii* vs ω_{RBM} plot comparing experimental results from experiments on SDS wrapped SWNTs in solution. (b) The revised Kataura plot [Jorio 2005-075401]

2.5.5 Thermogravimetric analysis (TGA)

TGA is an analytical technique used to determine a material thermal stability has been used to characterize carbon nanotubes for over a decade [Landi 2005-6819]. It is often used to analyze the resulted SWCNT samples by synthesis and purification methods and is also a popular technique for the determination of the amount of metal catalyst in CNT sample. The widespread acceptance of this method is mainly resulted from the simplicity of using a representative sample and evaluating the changes in weight loss in a flowing air as a function of temperature. In addition, it is the most common used method for calculating the metal-catalyst impurity levels.

As shown in Fig. 2-19, the relative amount of different fraction in CNT sample are normally indentified from interpretation for TGA data if their different fractions in sample are well separated, and the weight derivative curve have been used to analyze their fractions in terms of CNTs, amorphous carbon, and graphitic nanoparticles according to their various decomposition temperatures obtained from the peak value of the weight derivative curve \int^{Zhang} 2004-149, Hu 2003-13838, Harutyunyan 2002-8671, Shi 1999-35, Landi 2005-6819]. SWCNTs could decompose in the range from 300 to 500 $^{\circ}C$ [Zhang 2004-149]. HiPco MWCNTs could decompose at temperature approximately ~ 600 °C [Musso 2007-1183, Dileo 2007-064307]. Besides the main combustion temperature, some satellite peaks could be observed at lower temperature. suggested from previous studies, when MWCNTs are treated by various acid treatments, it is suggested that

derivative peak temperatures observed at \sim 350 °C might have resulted from additional carbonaceous impurities which are introduced by the destruction of nanotubes during acid treatments [Zhang 2004-149, Hu 2003-13838, Harutyunyan 2002-8671, Shi 1999-35]. Additionally, the peak below 300 $^{\circ}$ C is typical of residual acid and absorbed water in the sample after treatment [Landi 2005-6819] .

According to the study of Zhang et al., when SWCNTs are sonicated in nitric acid up to 4 h, the derivative peak increases from 450 to 480 $^{\circ}$ C as the treatment time increases to 2 h, and the peak decreases to 420 $^{\circ}$ C as the treatment time increases to 4 h $^{[Zhang 2004-149]}$. The peak temperature of MWCNTs also change according to various treatment conditions [Musso 2007-1183] .

Chapter 3

Experimental methods

Various processes were used to facially modify the MWCNTs. The processes included the ion treatment, a two-step process combining the ion pretreatment and followed by a dilute nitric acid (0.25 M HNO_3) treatment, and the acid treatments which sonicated CNTs in nitric/sulfuric (HNO₃/H₂SO₄=1/3 (v/v)) or dilute nitric (0.25 M HNO₃) acids with various process times. The details of the experimental flow chart, the experimental procedures, and surface and structure characterizations are illustrated in the following sections.

3.1 Experimental flow chart

Figure 3-1 depicts the experiment flowchart for each step of the surface modification processes and analysis methods for as-purchased MWCNTs. The MWCNTs were treated by acid treatment using $HNO₃/H₂SO₄ (= 1/3 v/v)$ or 0.25 M $HNO₃$ acid solution with various process time, the ion treatment applying H_2/O_2 gas mixture with various gas flow ratios, and the ion pretreatment and followed by a 0.25 M HNO₃ acid treatment. Each acid treatment was followed by a cleaning and drying procedures in air.

Fig. 3-1 Experiment flowchart

3.2 Raw materials and processing operators

SEM and TEM images of as-purchased CNTs

The CNTs, provided by a commercial company, were grown by thermal chemical vapor deposition. As shown in Fig. 3-2 and 3-3, the SEM and TEM images shows that the CNTs are highly tangled with multiple layers and diameters ranging from 15 to 40 nm.

Fig. 3-3 TEM images of as-purchased CNTs: (a) at lower magnification, (b) at higher magnification

XPS analysis of as-purchased CNTs

Fig. 3-4 XPS C_{1s} spectrum of the as-purchased CNTs

The XPS C_{1s} spectrum of the as-purchased CNTs was recorded and is shown in Fig. 3-4. Based on the previous studies ^[Felten 2005-074308, Ago 1999-8116], the spectra are deconvoluted into five Gaussian peaks centered at 284.5, 285.1, 286.2, 287.2, and 288.9 eV. Here, the main peak at 284.5 eV originates from a graphite signal. The peak at 285.1 eV is attributed to sp³ carbon a na ti [Felten 2005-074308, Xu 2007-8945] . The peaks at 286.2, 287.2, and 288.9 eV correspond to hydroxyl, carbonyl (or ether), and carboxyl (or ester) groups respectively. A peak attributed to π - π ^{*} shake-up bonds is observed at 290.4 eV $\frac{\text{[Jonescu 2006-36, Zhang 2007-2366]}}{\text{[onescu 2007-2366]}}$; and the peak at 283.2 eV originates from carbidic carbon [Wiltner 2004-881]. Meanwhile, the deconvolution results also show that the oxygen functional groups have been grafted onto the surface of the pristine MWCNTs with a concentration of approximately 11.2 %. This is consistent with the description provided by the vendor that the raw materials were treated using mild acids prior

to shipment. Furthermore, the results show that the CNTs are still composed of approximately 40 % sp^3 content as shown in table 4-1.

Raman spectra of as-purchased CNTs

As shown in Fig. 3-5, with two characteristic peaks , D and G bands, the Raman spectrum shows that the I_D/I_G of the as-purchased CNTs is approximately 0.89. Due to the absence of RBM signal, the Raman spectra further confirms that the CNTs are MWCNTs.

TGA of as-purchased CNTs

The TGA curve in Fig. 3-6 reveals that the as-purchased CNTs are oxidized from approximately 450 to 650 $^{\circ}$ C. It also shows that the catalyst shares around 5 wt. % in the material. Meanwhile, the weight derivative TGA curve shows a main decomposition peaked at 600° C. tra 16

Fig. 3-5 Raman spectrum of the as-purchased CNTs

Fig. 3-6 TGA curve for the as-purchased CNTs

 Other raw materials and processing apparatus: ALLELLE

The chemicals and processing apparatus used in this study are as follows:

3.3 Acid treatment procedures

When the MWCNTs were treated by the nitric/sulfuric acid treatment, 0.02 g as-purchased MWCNTs were immersed in 10 ml $HNO₃/H₂SO₄ (=1/3 (v/v))$ solution and the CNTs/acid mixtures were then ultrasonicated for 6 and 9 h at room temperature. Alternatively, when MWCNTs were treated by the dilute acid treatment, CNTs were prepared with 0.02 g and immersed in 10 ml 0.25 M HNO₃ solution. The CNTs/acid mixtures were then ultrasonicated for 2 h at room temperature. Subsequently, the mixtures were diluted with deionized water separately and filtered by using a 0.2 μm porous polytetrafluoroethylene (PTFE) membrane disc to remove the excess acid from the solution. At last, all deposited black powder were washed from the disc filters using ethanol and then dried at 160 °C on a hotplate in air for 30 min. The details of the specimen designations for the MWCNTs treated by nitric/sulfuric or dilute nitric acid treatments, and the treatment conditions and sequences are listed in Table 3-1.

3.4 The ECR plasma system for ion treatment

Microwave discharge system can provide concentrated plasma with ion densities of more than $3x10^{11}$ cm⁻³. This can be used for many plasma processes highly efficiently. The frequency most often used is 2.45 GHz. It is the same as the often used microwave oven at home today. ECR plasma system has been a popular etching method in many applications because, with divergent magnetic flux and high bias voltage, this system can possess excellent features of high ionization efficiency, high density plasma generation in low-pressure vacuum, and effective plasma ion extraction and transportation [Matsuo-1982-L4]. These give the advantages that the positive or negative ions can be easily extracted and transported toward the specimen with high incident energy; the specimen can be placed far from plasma sheath and then treated at relative low temperature. These advantages are very important for conducting highly efficient etching process to create high density free radical bonds on nanotube surface but causing no severely structural damage of the specimen.

Fig. 3-7 Schematic of the ECR plasma system for ion treatment

Figure 3-7 reveals the microwave ECR plasma system for the surface modification of CNTs. 2.45 GHz microwave was introduced into the plasma chamber through a quartz window. The output power of the microwave generator was set at about 750 W. The magnetic coil was arranged around the periphery of the chamber and the magnetic flux density was 875 Gauss to meet the ECR condition at the microwave frequency used. Before treatment, the system was pumped down to 10^{-6} Torr first. To ensure a sufficient density of plasma and an adequate mean free path, during the treatment process, chamber pressure was held at 4.2×10^{-3} Torr. A bias voltage of -250 V was applied to the stage, which is 28 cm below plasma zone, to extract and accelerate the hydrogen and oxygen cations with high incident energy [Ni-2000-R16343]. Resistance heater is wired around the process stage. Thermocouple is also connected to process stage to measure the process temperature set.

	Ion treatment ^a			Acid treatment ^b	Drying ^c					
Specimen designation	H_2/O_2 flow ratio (sccm/sccm)	Process time (min)	solution	Sonication Temperature $({}^0C)$	Sonication time (min)	Set temperature $({}^0C)$	Heating time (min)			
A1			$HNO3/H2SO4$ $=1/3$ (v/v)	Room temp	360	160	30			
A2	No ion treatment				540					
A3			0.25 M HNO ₃	Room 120 temp		160	30			
B1	50/0									
B2	40/10									
B ₃	25/25	5	No acid treatment							
B4	10/40									
B ₅	0/50									
B6	25/25	20								
C1	50/0		μ							
C ₂	40/10	E		Room \blacksquare temp	120	160	30			
C ₃	25/25	5	0.25 M HNO ₃							
C ₄	10/40									
C ₅	0/50									

Table 3-1 Specimen designations and their treatment conditions and sequences

^a Other ion treatment conditions: crucible temperature and bias voltage: 400 °C and -250 V; base pressure: 10^{-6} Torr; working pressure: 4.2×10^{-3} Torr; microwave power: 750 W b MWCNT concentration: 0.002 g in 10 ml solution</sup>

^c D.I. water cleaning and drying by a hotplate in air after acid treatment

3.5 Ion treatment procedures

As shown in Fig. 3-7, 0.05 g samples of as-purchased MWCNTs were transported in a 304 stainless steel crucible and placed on the process stage in the vacuum chamber of the ECR plasma system. H_2/O_2 gas flows were fed as etching gases with controlled ratios of 50/0, 40/10, 25/25, 10/40, and 0/50 (sccm/sccm), which are equivalent to H_2 concentrations of 100, 80, 50, 20, and 0 vol %, respectively. Once the stage temperature reached 400 $^{\circ}$ C, the plasma treatment was conducted for 5 and 20 min.

The details of the specimen designations for the MWCNTs treated by the ion treatment and the two-step process combining the ion and dilute nitric acid treatments, and the treatment conditions and sequences are also listed in Table 3-1.

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3.6 CNTs characterization

3.6.1 Scanning electron microscopy (SEM)

In order to observe the morphology changes, the samples of pristine MWCNTs and the MWCNTs treated by the ion and acid treatments were measured by using a SEM (JOEL, JSM-6500F). Before the measurement, each sample was sonicated in ethanol for 30 min and dispersed onto a silicon wafer.

3.6.2 Transmission electron microscopy (TEM)

The microstructures of the MWCNTs samples were characterized by TEM (JEOL JEM-2100). The samples were prepared by dispersing and then depositing the black powder on lacy carbon grids by using ethanol. Prior to characterization, all samples were dried by a hot plate for 30 min at temperature of 160 °C.

3.6.3 X-ray photoelectron spectrometer (XPS)

XPS (Perkin-Elmer model PHI 1600) was performed to determine the chemical changes on the surface of nanotubes. Prior to measurement, each specimen was attached to Scotch tape to avoid dispersion of the nanotubes in the vacuum chamber. Monochromated Al Kα radiation (hv=1486.6 eV) was used as the photon source and photoelectrons were collected at an angle of 54.7° relative to the normal direction of the specimen surface. The energy resolution of the system was set to 0.2 eV. During C_{1s} spectrum analysis (Spectral Data Processor (SDP) v4.0, XPS international, LLC), background noise was subtracted by using the "Linear" mode in the range between 281.5 and 293 eV, and the component peak fitting was performed by using Gaussian line shapes.

890 **3.6.4 Raman spectroscopy**

In this study, Raman spectroscopy (Jobin YVON LabRam HR800) is used as a rapid way to monitor the structure change of MWCNTs before and after treatments. As-purchased MWCNTs and the MWCNTs treated by various treatments are deposited on silicon wafers by using ethanol and dried on hot-plate in air for 30 min at temperature, 160 °C. The exciting source was an Ar laser (514 nm) focused (50x) to a 2 μm spot size. All spectra were collected with five accumulations of 3 s each.

3.6.5 Thermogravimetric analysis (TGA)

TGA (TA Q500) was used to characterize the changes in thermal stability. Sampling weight of 0.01 g of each sample was placed in a platinum pan balance. A heating rate was set as 10 \degree C/min and ramped from room temperature to 800 \degree C under air flow (60 mL/min).

Chapter 4

Results and discussion

4.1 Effect of treatment time and solution composition on morphologies of the acid-treated MWCNTs

The SEM morphologies on the MWCNTs treated by the nitric/sulfuric acid for 6 and 9 h are in Figs. 4-1(a) to (b), respectively, under two magnifications. After the nitric/sulfuric acid treatment for 6 and 9 h, the morphologies of the acid-treated MWCNTs can be observed a significantly changed. It is observed that the nanotubes are cut by the treatment as the process time increases. In contrast to the as-purchased MWCNTs (Fig. 3-2a), the diameter distributions are also changed from original range between 15 and 40 nm to range between 25 to 40 nm when the MWCNTs are treated for 9 h. This leads to a larger mean diameter than that of the as-purchased MWCNTs. These results match previous studies which suggest that the harshness of the acid treatment reduces the length, narrows the diameter distribution, and increases the average tube diameter of the CNTs^[Zhang 2004-149, Dumitrescu 2007-12944]. In addition, it was also observed that more impurities are introduced by this treatment. It is suggested that, because the acid treatment often combines the unwanted side effects of damage to the sidewalls as well as length reduction of the nanotubes, these impurities may be by-products resulted from the severe structural damage [Hu 2003-13838, Zhang 2004-149]

Alternatively, as shown in Fig. 4-2, the SEM images show that, when the as-purchased MWCNTs are only treated by 0.25 M HNO₃ for 2 h, a slightly greater number of larger diameter nanotubes can be seen in the mild acid treated sample. This also results in a slightly larger mean value of the diameter distribution than that of the as-purchased MWCNTs. However, the diameter distribution and morphology change of the MWCNTs treated by the dilute acid is insignificant.

Fig. 4-1 SEM morphologies of MWCNTs after different acid treatment times, (a) 6 h; (c) 9 h (Specimens A1 and A2, respectively), where (b) and (d) are corresponding SEM images of (a) and (c) respectively at higher magnification.

Fig. 4-2 SEM images of the 0.25 M HNO₃ acid-treated MWCNTs (Specimen A3).

Fig. 4-3 SEM images for the ion-treated MWCNTs specimens for different H₂/O₂ flow ratios, (a) 50/0, (b) 40/10, (c) 25/25, (d) 10/40, (e) 0/50 and (f) 25/25 (sccm/sccm), (Specimen B1 to B6, respectively).

Fig. 4-4 SEM images for the ion-treated MWCNTs specimens for different H_2/O_2 flow ratios, (a) 50/0, (b) 40/10, (c) 25/25, (d) 10/40, (e) 0/50 and (f) 25/25 (sccm/sccm) (Specimen B1 to B6, respectively) at higher magnification.

4.2 Effect of H2/O2 flow ratio on morphologies of the ion-treated MWCNTs

In contrast to the SEM characterization results of the nitric/sulfuric and dilute nitric acid-treated MWCNTs, after the ion treatment with various H_2/O_2 flow ratios, as depicted in Figs. 4-3 and 4-4 with different magnifications, the morphologies and the diameter distributions of the ion-treated samples do not show any observable difference in comparison with those of the as-purchased sample (Fig. 3-2a). This depicts that the ion treatment has no negative effects on morphology of the MWCNTs.

4.3 Effect of ion pretreatment on MWCNTs morphologies by two-step

process

Figures 4-5 and 4-6 reveals the SEM images when the ion-pretreated MWCNTs by using various H_2/O_2 flow ratios are further ultrasonicated in a dilute acid (0.25 M HNO₃) for 2 h. As shown in the Fig. 4-5, the MWCNTs treated by the two-step process are observed to be with no difference in morphology as compared to that of the as-purchased MWCNTs. Meanwhile, further observing the figures at higher magnification (Fig. 4-6), the results show that, after being treated by the process under various H_2/O_2 gas flow ratios, a slightly greater number of larger diameter nanotubes can be seen in the samples treated by the process. This results in a larger mean value of the diameter distribution. This could be because, after the ion pretreatment, the nanotubes can be with higher density free radical bonds so that nanotubes with smaller diameter could be more easily destructed in the dilute nitric acid due to their relatively low oxidation stability. However the effect is shown to be insignificant. This shows that, although the two-step process, combining the ion pretreatment and a 0.25 M HNO₃ acid treatment, may also possibly damage the side walls of the nanotube but this side effect is almost negligible.

Fig. 4-5 SEM images for the ion-pretreated MWCNTs specimens for different H_2/O_2 flow ratios, (a) 50/0, (b) 40/10, (c) 25/25, (d) 10/40 and (e) 0/50 (sccm/sccm) (Specimen C1 to C5, respectively), and followed by a 0.25 M HNO₃ acid-treatment.

Furthermore, in contrast to the results of the MWCNTs only treated by the dilute acid for 2 h in Fig. 4-2, the diameter distribution change, which results in more nanotube with large diameter, of the two-step process is relative higher. This further supports that the free radical bonds introduced by the ion treatment can increase the size distribution change while the ion-pretreated MWCNTs are further treated in the dilute acid. In addition, it is also found that, with and without the ion treatment, the nanotube reductions in length for all samples are observed to be insignificant when MWCNTS are treated in the dilute acid treatment.

4.4 TEM microstructures

Fig. 4-7 TEM image of merely ion-treated MWCNTs (Specimen B3).

Fig. 4-8 TEM image of merely ion-treated MWCNT (Specimen B3) at higher magnification.

Figure 4-7 and 4-8 shows the TEM image of the MWCNTs (Specimen B3) treated by the ion treatment with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) for 5 min. As revealed in Fig.

4-8, the images at higher magnification support the fact that, after the ion treatment, the microstructure of the nanotubes are shown no difference compared with that of the as-purchased sample (Fig. 3-3b).

The SEM and TEM results depict that the effect of ion treatment and the two-step process on MWCNTs morphology and structure are insignificant. However, it is noted that, theoretically, SEM and TEM can not observe the functional groups nor precisely predict the formation of the free radical bonds if the "very small" defects are formed in the chemical structure of the surface.

4.5 XPS spectra

In order to investigate the functionalization extent, the C_{1s} spectra of the nitric/sulfuric acid-treated MWCNTs are shown in Fig. 4-9, and the deconvolution results are given in Table 4-1. Note that the [O]/[C] ratio in the table is based on the relative percentage of three carboxyl groups to all the carbon species detected [Ago 1999-8116, Xu 2007-8945]. As can be seen in Fig. 4-9 and Fig. 3-3, it is observed that when the as-purchased MWCNTs (Fig. 3-3) are treated by $HNO₃/H₂SO₄$ solution for 6 and 9 h, the C_{1s} spectrum is apparently shift to higher binding energy. More specifically, the deconvolution results reveal that the share percentages of the oxygenated carbon species are higher after the nanotubes are treated by the acid treatment; and the [O]/[C] ratio increases as the process time increases from 6 to 9 h (46.2% to 52.7% respectively) while the sp³ carbon are reduced to 26.4% and 24.5% and sp² are reduced to 27.5% and 22.6%, respectively. Suggested by Felten et al. [Felten 2005-074308], the sp³ content peaking at 281.5 can be attributed to amorphous carbon.

Fig. 4-9 XPS C_{1s} spectra of the acid-treated MWCNTs under different treatment times, (a) 6h, and (b) 9 h (for Specimens A1 and A2, respectively).

After the as-purchased MWCNTs are treated by the ion treatment for 5 min using various $H₂/O₂$ gas flow ratios, the XPS survey spectra are shown in Fig. 4-10. It is noted that the spectra showing the presence of carbon and oxygen on the treated and untreated samples are normalized with respect to C_{1s} intensity for comparison purposes. In contrast to the spectrum of the as-purchased MWCNTs, a higher concentration of oxygen is introduced to the surface of the nanotubes treated by the ion treatment using any gas flow ratio.

Fig. 4-10 XPS survey spectra of the 5 min ion-treated MWCNTs under different H_2/O_2 flow ratios (for Specimens B1 to B5).

Fig. 4-11 XPS C_{1s} spectra of the 5 min ion-treated MWCNTs under different H_2/O_2 flow ratios (for Specimens B1 to B5).

Fig. 4-12 XPS C_{1s} spectrum of the 20 min ion-pretreated MWCNTs (Specimen B6) and its deconvoluted spectra.

	\mathbf{r}					Τ,		
	XPS*							TGA
Specimens			$C-O$	$C = O$	COO		Raman	Decomposition
designation	sp^2	sp^3				$[O]/[C]^*$	(I_D/I_G)	temperature ⁺
	$(\%)$	(%)	$(\%)$	(%)	(%)	$(\%)$		(^0C)
As-purchased	48.8	40	$\mathbf{1}$	8.4	1.8	11.2	0.89	600
A1	27.5	26.4	19	16.7	10.5	46.2	0.96	635
A2	22.6	24.5	15.7	28	9	52.7	0.96	638
A ₃	23.5	57.1	6.4	4.3	14.1	24.8	0.91	684
B1	30.8	54	2.1	11	2.2	15.3	1.08	596
B2	36.8	49.1	0.6	0.5	12.9	14	1.27	594
B ₃	42.8	26.1		13.8 17.3	$\mathbb{L}_{\leq 0.1}$	31.1	1.07	595
B4	40.5	39.5	-11.9	0.8	7.3	20	1.05	599
B ₅	44.2	44.6	< 0.1	9.4	1.7 ø,	11.1	1.03	598
B6	27.1	13.E	24.3	32.3	3.2 ν	59.8	$\mathbf{1}$	594
C1	59.5	$21.1 -$	4.4.		$9.2 = 8.9$	19.5	1.06	651
C ₂	43.6	32.3	10.7	2.7	10.7	24.1	0.95	677
C ₃	37.1	10.6	32	18.2	2.2	52.4	1.26	684
C ₄	33.4	19.1	26.2	18.8	2.5	47.5	1.13	682
C ₅	44.2	32.9	9.2	8.2	5.5	22.9	0.96	668

Table 4-1 Comparisons of the XPS, Raman I_D/I_G, and TGA peak temperature for MWCNTs specimens merely treated by ion and/or acid processes.

[O]/[C]: total percentage of oxygenated carbon species to the total number of carbon species detected.

⁺ Corresponding to the peak temperature of weight derivative curve.

*Represents the percentage of each carbon containing species in the MWCNTs specimens.

For a detailed comparison, all C_{1s} spectra of the MWCNT samples are presented in Fig. 4-11 and the deconvolution results are summarized in Table 4-1. After the samples are treated by the ion treatment, the XPS measurements show that the concentrations of the graphite, $sp²$ and $sp³$ carbons, and oxygen-containing functional groups are different according to the gas mixture composition. Also, it is clear that when the samples of the MWCNTs are treated with a H_2/O_2 gas flow ratio of 25/25 (sccm/sccm), the highest concentration of oxygenated functional groups is achieved whilst the concentration of $sp³$ carbon is minimized. Meanwhile, the $sp²$ carbon is insignificantly decreased.

The C_{1s} spectrum of the MWCNTs treated by the ion treatment with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) for 20 min is presented in Fig. 4-12. The results listed in Table 4-1 reveal that the [O]/[C] ratio is extremely high up to 59.8% and the $sp³$ carbon is only with 13.1% while the morphology (cf. Fig. 4-3f and 4-4f) is almost the same as that of the as-purchased MWCNTs (Fig. 3-2). In contrast to the results of the MWCNTs merely treated by nitric/sulfuric acid for 9 h, the MWCNTs treated by the ion treatment with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) for 20 min are with higher [O]/[C] and sp^2 values (Table 4-1).

As shown in Fig. 4-13, all XPS C_{1s} spectra of the MWCNTs pretreated by the ECR ion pretreatment with various H_2/O_2 gas flow ratios and followed by a 0.25 M HNO₃ acid treatment for 2 h are presented. It is seen that there are shifting for all MWCNTs specimens on the carbon signals of XPS spectra varied by various flow ratios. The results in Fig. 4-13 and Table 4-1 also show that when the MWCNTs are pretreated with H_2/O_2 gas flow ratios of 25/25 and 10/40 (sccm/sccm) (for Specimen C3 and C4 respectively) the [O]/[C] ratios are 42.4% and 52.4% while sp^3 carbon are reduced to 10.6% and 19.1% respectively. Meanwhile, the $sp²$ carbon of both the specimen are significantly higher than the results of the MWCNTs only treated by nitric/sulfuric acid for 6 and 9 h (Specimen A1 and A2 specifically). These results depict that the two-step method is significantly capable of facially functionalization and purification for removing the carbon impurities generated by synthesizing process simultaneously on the nanotube surface. In contrast to the MWCNTs merely treated by the ion treatment with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) for 5 min (Specimen B3, cf. Table 4-1), the results support the fact that the two-step method, which combines the ion pretreatment with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) for 5 min and followed by a 0.25 M HNO₃ acid treatment for 2 h (Specimen C3), has higher capability of facially functionalizing and purifying nanotubes. In addition, by comparing the results of the MWCNTs treated by the ion treatment with H_2/O_2 flow ratio of 25/25 (sccm/sccm) for 20 min (Specimen B6), the $[O]/[C]$ ratio and $sp³$ values of the MWCNTs treated by the two-step process with using the same H_2/O_2 gas flow ratio (Specimen C3) are almost the same as that of Specimen B6 but the $sp²$ carbon of Specimen C3 is significantly higher than that of the Specimen B6. This further confirms that the functionalization and purification capability of this method is significant, only the process time is longer than that of the ion treatment.

Fig.4-13 XPS C_{1s} spectra of the 5 min ion-pretreated MWCNTs and followed by a 0.25 M $HNO₃$ acid treatment (for Specimens C1 to C5).

As presented in Table 4-1, it is shown that the [O]/[C] ratio of the MWCNTs treated only with the 0.25 M HNO₃ acid treatment (Specimen A3) is obviously smaller than the results of the MWCNTs that underwent ion pretreatment alone by H_2/O_2 flow ratio of 25/25 (sccm/sccm) for 5 min. This supports and confirms that in this case, the effect of the ion pretreatment is significant on the functionalization of MWCNTs by the dilute acid treatment.

As compared to the results of the MWCNTs treated by only ion treatment with H_2/O_2 gas flow ratio of $25/25$ and the two-step process with the same gas flow ratio, the $HNO₃/H₂SO₄$ acid treatment reveals to be low facially functionalization and purification efficiencies. Thus, it is found that both the two presented methods are effective ways to graft polar functional groups onto the nanotubes while the removal of sp^3 and the increase of sp^2 are also significant.

4.6 Raman spectra

In general, functional groups are expected to be covalently bonded to free radical bonds on the surface of CNTs ^[Banerjee 2003-1899]. Therefore, higher density of free radical bonds is important for allowing more functional groups to form on nanotube surface. In order to evaluate the formation of free radical bonds on nanotube surface by the various treatments, the Raman spectra are presented in Figs. 4-14, 4-15, and 4-17.

Fig. 4-14 Raman spectra of the acid-treated MWCNTs under different treatment times (for Specimens A1 and A2).

As shown in Fig.4-14, the Raman spectra of the MWCNTs treated by $HNO₃/H₂SO₄$ solution for 6 and 9 h are presented with two characteristic peaks which are attributed to the D and G bands. The spectra have been normalized with respect to the G band for comparison. Suggested by previous studies, the intensity of the D band, at frequencies around $1,344 \text{ cm}^{-1}$, is correlated with structural disorder of CNTs, which originates from the defects including disordered materials, poor graphitization, functionalized carbon, and the amorphous carbon on
the sidewall of nanotubes [Shaijumon 2007-75, Dillon 2004-691, Jian 2008-230]. The G band at frequencies around 1,572 cm⁻¹ is activated by the graphite signal $\left[\frac{\text{Jian 2008-230}}{\text{Jian 2008-230}}\right]$. It is also suggested that the I_D/I_G ratio is closely associated with the defect density on the walls of the MWCNTs $[Jian]$ ^{2008-230]}. Therefore, the intensity ratio can be used to evaluate the formation of free radical bonds which are preferential sites for functionalization. The results of the I_D/I_G ratio are also listed in Table 4-1. The results show that when the as-purchased MWCNTs are treated by the acid for 6 and 9 h, both the I_D/I_G ratios are 0.96.

Fig. 4-15 Raman spectra of the 5 min ion-treated MWCNTs under different H_2/O_2 flow ratios (for Specimens B1 to B5).

In order to evaluate the effects of the H_2/O_2 gas flow ratio on the formation of free radical bonds on the nanotube surface when the MWCNTs are treated by the ion treatment, the Raman spectra of the as-purchased and the ion-treated MWCNTs are presented in Fig. 4-15. As expected, in contrast to the as-purchased sample, all I_D/I_G ratios are increased after ion treatment with any H_2/O_2 gas flow ratio. As shown in Fig. 4-16, the I_D/I_G ratio increases from 1.03 to 1.27 when H_2 concentration increases from 0 to 80 vol. %. The H_2/O_2 gas of 50/0, 40/10, 25/25, 10/40, and 0/50 (sccm/sccm) are equivalent to H_2 concentrations of 100, 80, 50, 20, and 0 vol. %, respectively.

Fig. 4-16 I_D/I_G ratio of the 5 min ion-treated MWCNTs vs. H₂ concentration in H₂/O₂ flow.

Note that the ion density is very important for the formation of the free radical bonds on the surface and the oxygen cation in the ion stream is crucial for forming oxygen-containing functional groups. By comparing the ionic current, it is found that current increases from 0.12 to 0.47 A while the H_2 concentration increases from 0 to 100%. Note that the ionic current correlates with the ion density and is measured by an ammeter connected to the 150 mm diameter process stage. This shows that the ion density of the cation stream increases as H_2 concentration increases. This leads to higher I_D/I_G ratio when H_2 concentration of the gas flow is higher. However, this simultaneously reduces $[O]/[C]$ value due to the decreases on oxygen cations in the ion stream. Apart from their involvement in ion bombardment, the generated oxygen cations can also act as highly reactive chemical species which form covalent bonds with the amorphous carbon and then nanotube surface. More specifically, the amorphous carbon layer is more reactive than the cylindrical walls to form volatile products with the oxygen cations. The products are then pumped out by the vacuum system. Thus, as shown in Table 4-1, the ion treatment using a H_2/O_2 mixture can increase the concentration of oxygenated functional groups whilst also reducing the $sp³$ value. On the other hand, treatment with pure O_2 gas (with the exception of increasing the I_D/I_G ratio) does not yield any other obvious effects in regard to the sp^2 and [O]/[C] values of CNTs when compared with the as-purchased MWCNTs. This indicates that a H_2/O_2 mixture not only facilitates free radical bonds but also promotes covalent bonding in this case. Therefore, even with the addition of 20 vol. % H₂ (H₂/O₂ = 10/40 (sccm/sccm)) in gas flow, there is still a significant removal of amorphous carbon and formation of oxygen-containing groups on the nanotube surface.

In contrast to the results of the MWCNTs treated by $HNO₃/H₂SO₄$ solution for 9 h (Specimen A2), as listed in Table 4-1, after the MWCNTs are treated by the ion with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) for 5 min, the measurement of Raman spectroscopy displays a higher I_D/I_G ratio (1.07) than that of Specimen A2 (0.96). This increase may reflect the fact that the ion treatment can introduce higher density of free radical bonds than the nitric/sulfuric acid treatment on the surface of the nanotubes effectively. However, it is observed that when the process time of the ion treatment increases to 20 min (Specimen B6), the I_D/I_G ratio value decreases to 1.00. As suggested by Osswald et al. [Osswald 2007-728], this decrease might be due to the removal of the impurities coating on the surface of the 1896 MWCNTs.

Raman spectra of the MWCNTs treated by merely dilute acid treatment for 2 h and the two-step process combining the 5 min ion treatment with various H_2/O_2 gas flow ratios and the dilute acid treatment are presented in Fig. 4-17. The resultant I_D/I_G ratios are also listed in Table 4-1. The results show that, when the as-purchased MWCNTs are only treated by the dilute acid treatment, both the I_D/I_G and $[O]/[C]$ ratios can only slightly increase. However, when the MWCNTs are treated by the ion pretreatment and further treated by the dilute nitric acid treatment for 2 h, the MWCNTs can be with much higher I_D/I_G values. The increase of the I_D/I_G ratio indicates that higher density of free radical bonds can be induced by the ion pretreatment. This also supports the hypothesis that the ion treatment is very effective in creating free radical bonds on the nanotubes; and free radical bonds could only be introduced on the outer surface by the treatment because the incident ions do not reach the inner shells of the nanotubes.

Fig. 4-17 Raman spectra of the 5 min ion-pretreated MWCNTs and followed by a 0.25 M $HNO₃$ acid treatment (for Specimens C1 to C5). a tillillis a

Additionally, as compared the results of Specimen B3 (cf. Table 4-1), when the MWCNTs are treated by the ion pretreatment with H_2/O_2 gas flow ratio of 25/25 for 5 min and further treated by 0.25 M HNO₃ acid for 2 h (Specimen C3), the I_D/I_G ratio (1.26) of Specimen C3 is apparently higher than that of Specimen B3 (1.07). The [O]/[C] ratio is also increased from 31.1 % (Specimen B3) to 52.4 % (Specimen C3). These results support the fact that, with the ion pretreatment, high amount of oxygen-containing functional groups can be effectively introduced on nanotube surface by the dilute acid treatment. It is also shown that the I_D/I_G ratios of the MWCNTs treated by the two-step process are varied with different H_2/O_2 gas flow ratio. However, it is found that there is no correlation between I_D/I_G ratio and $H₂$ concentration in gas flow.

It should be noted that, as the presence of measurement uncertainty is found to be relative high, Raman spectroscopy is invalid to quantify the formation of free radical bonds and there is still no sufficient evidence to support this. Therefore, in this study, we are using XPS for the functionalization quantification results. However, as suggested by previous studies ^[Dillon 2004-691, Osswald 2007-728, Jian 2008-230], it is still a good indicator to monitor the formation of free radical bonds.

4.7 TGA results

It is known that the oxidation stability correlates with the combing effect of defects and the diameter of the nanotubes $\frac{[Zhang\ 2004-149, Xu\ 2007-8945, Liu\ 2007-5006, BOM\ 2002-615]}$. The presence of defects in graphite contributes to a decrease in the oxidative stability of the material ^{[BOM} $2002-615$]. In addition, the larger the diameter is, the higher the oxidation stability of the nanotubes is ^[Zhang 2004-149, BOM 2002-615]. Theoretically, SEM and TEM can not observe the functional groups nor precisely predict the formation of free radical bonds if the "very small" defects are formed in the chemical structure of the surface. Because defects and derivatization moieties in nanotube walls result in lower structural integrity and can lower the thermal stability [Pillai 2007-3011, Liu 2007-5006], it is useful to confirm the results by using TGA.

Fig. 4-18 TGA curves for the acid-treated MWCNTs under different treatment times, (a) 6 h, and (b) 9 h (for Specimens A1 and A2, respectively).

As revealed in Fig. 4-18, the mainly derivative peak temperatures of the MWCNTs treated by nitric/sulfuric acid process for 6 and 9 h are shown to be 635 and 638 $^{\circ}$ C, which are much higher than that of the as-purchased MWCNTs (600 $^{\circ}$ C). As supported by the results of SEM, it is suggested that the increase of the decomposition temperature may be dominated by

the significant diameter distribution change. Meanwhile, it is observed that there are satellite peaks presented at ~ 250 and ~ 350 °C in weight derivative TGA curves. The presence of the satellite peak of the derivative curve at ~ 350 °C might have resulted from additional carbonaceous impurities which are introduced by the destruction of nanotubes during acid treatments [Zhang 2007-149, Hu 2003-13838, Harutyunyan 2002-8671, Shi-1999-35]. Additionally, the peak below 300 $^{\circ}$ C is typical of residual acid and absorbed water in the sample after treatment [Landi $2005-6819$. The presence of the satellite peaks are supporting the fact that the structural damage are severe when the nitric/sulfuric acid are used to facially modify the MWCNTs and this matches the SEM characterization results in Fig. 4-1. Meanwhile, as revealed in the figures, the TGA curve depicts that the carbon impurities introduced weight approximately 20% in 6 h acid-treated sample and 30% in 9 h acid-treated sample. The weight percentages of the catalysts are also found to be increased to 7% and 13% for the MWCNTS treated by acid for 6 and 9 h respectively (for Specimen A1 and A2 respectively). This shows that the structural damage increases as the acid treatment time increases. Therefore, the graphite structure are damaged and removed by filter during cleaning process. So the share percentage of catalyst is thus raised up.

Figure 4-19 shows the TGA curves of the MWCNTs treated by the ion treatment for 5 min with various H_2/O_2 gas flow ratios. It is found that all curves of the ion-treated MWCNTs

are almost overlapping on the curve of the as-purchased MWCNTS only the MWCNTS treated by H_2/O_2 gas flow ratio of 50/0 (sccm/sccm) are slightly deviated from that of the as-purchased nanotubes because a very few percentage of the MWCNTS treated by H_2/O_2 gas flow ratio of 50/0 (sccm/sccm) are decomposed from temperature at 300 $^{\circ}$ C. However, the deviation is insignificant.

Fig. 4-20 Weight-derivative TGA curves for the 5 min ion-treated MWCNTs under different H_2/O_2 flow ratios (for Specimens B1 to B5).

Figure 4-20 shows the weight-derivative curves of TGA analysis on the as-purchased MWCNTs and the 5 min ion-treated MWCNTs. The results show that with a main decomposition temperature of 600 °C , the as-purchased MWCNT samples are the most thermally stable with respect to oxidative degradation. Correspondingly, the MWCNTs treated by the ion treatment with a gas composition of 40/10 (sccm/sccm) have the lowest decomposition temperature (594 $^{\circ}$ C). Because the oxidation stability is a function of the combined effect of defects and the diameter of the nanotubes, with the same diameter distribution observed by the SEM characterizations in Fig. 4-3, the results are in agreement with the hypothesis that the decrease of the oxidation reaction temperature is mainly a result of the free radical bonds produced by the ion treatment. The marginal differences of the main decomposition temperature between as-purchased and ion-treated samples reflect the fact that the effect of gas composition on structural integrity of the nanotubes is negligible in this case although the insignificant difference are varied with H_2/O_2 gas flow ratio.

Fig. 4-21 TGA curves for 0.25M HNO₃ acid-treated MWCNTs

Figure 4-21 reveals the TGA results of the MWCNTs are only treated by 0.25 M HNO₃ for 2 h. It is found that after the dilute acid treatment, carbon impurities including absorbed water are of approximately 15% in weight and the catalysts weight approximately 7% in the dilute acid-treated MWCNTs sample. Meanwhile, the main decomposition temperature peaks at 684 °C. This shows that this treatment is so moderate that the MWCNTS can be with high structural integrity and low free radical bonds introduced $(I_D/I_G = 0.93)$. This is also supported by SEM characterization (Fig. 4-2) in which the morphology change is insignificant after the dilute acid treatment while the diameter is slightly enlarged.

In order to evaluate the effects of the ion pretreatment on the decomposition temperature of the dilute acid-treated MWCNTs, all TGA and weight derivative TGA curves of the MWCNTs treated by the two-step process with various H_2/O_2 gas flow ratios are presented in Fig. 4-22 and 4-23. As shown in the figures, the largest carbon impurities share percentage is approximately 22 % when the MWCNTs are pretreated by the ion treatment with H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) (Specimen C3) but the main combustion region is apparently shifted to higher temperature region. This leads to the highest main decomposition

temperature at 684 °C which is the same temperature as the MWCNTS only treated by 0.25 M $HNO₃$ acid for 2 h (Specimen A3). The results show that, with the ion pretreatment, the MWCNTs can be treated in dilute acid with high [O]/[C] ratio and thermal stability while the process time is relative low in contrast to the strong acid treatment.

Fig. 4-23 Weight-derivative TGA curves of the 5 min ion-pretreated MWCNTs and followed by a 0.25 M HNO₃ acid treatment (for Specimens C1 to C5)

For comparison, TGA and weight derivative TGA curves of the MWCNTs treated by various treatments and time conditions are presented in Figs. 4-24 and 4-25. As shown in Fig. 4-24, in contrast to the TGA curves of the as-purchased MWCNTs and the MWCNTs only

treated by the ion treatment (Specimen B3), all TGA curves of the MWCNTs treated by any acid treatment present oxidative reaction in lower temperature region raging from 200 to 400 $\rm{^{\circ}C}$. As shown in Fig. 4-25, the satellite peaks of the weight derivative TGA curves show that this region could be contributed to carbon impurities. Meanwhile, the share percentage of the catalyst in the MWCNTs treated by $HNO₃/H₂SO₄$ acid for 9 h (Specimen A2) is significant higher than the specimens treated by other acid treatments.

Fig. 4-24 TGA curves of MWCNTs for different conditions, (a) as-purchased, (b) 5 min ion-treated (Specimen B3), (c) merely 0.25 M HNO₃ acid-treated (Specimen A3), (d) 5 min ion-pretreated and 0.25 M HNO3 acid-treated (Specimen C3), and (e) merely acid-treated

MWCNTs (Specimen A2).

Fig 4-25 Weight-derivative TGA curves of MWCNTs for different conditions, (a) as-purchased, (b) 5 min ion-treated (Specimen B3), (c) merely 0.25 M HNO₃ acid-treated (Specimen A3), (d) 5 min ion-pretreated and 0.25 M HNO₃ acid-treated (Specimen C3), and (e) merely acid-treated MWCNTs (Specimen A2).

According to the results of TGA, XPS and SEM characterization, although the

nitric/sulfuric acid treatment can introduce oxygenated functional groups on nanotube surface, the process is however censorable due to its high structural damage, long process time and solution wasting issues. This figure further depicts that, compared with the results of acid treatments, the ion treatment does not cause serious structural damage, and so the ion-treated sample can still be as the same thermal stability as the as-purchased sample.

According to the results of TGA, XPS in Table 4-1 and SEM characterization, the process combining the ion pretreatment applying H_2/O_2 gas flow ratio of 25/25 (sccm/sccm) and a 0.25 M HNO₃ post acid treatment for 2 h can yield significant advantages such as a very high [O]/[C] ratio and high thermal stability MWCNTs although nanotubes with high density free radical bonds resulted from the ion pretreatment can be possibly damaged during the dilute acid treatment.

It is noted that the presence of the uncertainties in the results of XPS and TGA may slightly change the data provided above. Uncertainty analysis based on sufficient experiments data are required to revise the process parameters if the proposed method is to be applied for practical uses. Although the analysis has not been conducted yet, the present results are still reliable enough to characterize the performance of this method qualitatively.

Chapter 5

Conclusions

This study proposed two new processes and compared with the traditional processes to functionalize MWCNTs, in order to expand the potential applications of CNTs. The examined processes include the acid treatment by dilute or nitric/sulfuric acid solution, the ion treatment and the ion pretreatment followed by a dilute nitric acid treatment. Table 5-1 summarizes the experimental results in terms of efficiency of functionalization ($[O]/[C]$, I_D/I_G), facial purification (sp^2) , TGA decomposition temperature, and structure damage. From the experimental results, the following conclusions can be drawn:

- 1. By comparing the degree of functionalization and structure damage of CNTs by nitric/sulfuric with that by dilute acid treatments, the results show that sonicating CNTs in nitric/sulfuric acid treatment leads to a greater functionalization with [O]/[C] values of 52.7% but too much structure damage (i.e. higher I_D/I_G ratios and lower decomposition temperatures, up to 0.96 and down to 638 °C), though the values of [O]/[C], sp² and I_D/I_G merely represent the near surface features due to limitation of penetration depth of XPS and Raman probes. Meanwhile, the chemical process is found to be with the drawbacks of pollution issue and too long treating time (up to 9 h).
- 2. When the MWCNTs are treated by the ion treatment, the results indicate that there are existence of maximum values of [O]/[C] and sp², and minimum values of I_D/I_G values at medium H_2/O_2 ratios. The existence of maximum functionalization is due to the competition between the amounts of free radical bonds on nanotube surface and oxygen cations in the ion stream. Meanwhile, it is also shown that the ion treatment causes no significant structure damage, and at treatment times of 5 and 20 minutes, the maximum

values of the [O]/[C] values are 31.1% and 59.8%, respectively, at medium H_2/O_2 ratio $(= 25/25$ (sccm/sccm)).

Table 5-1 Comparisons of the performance of the modification processes on structure damage and the ranges of [O]/[C] ratio, sp^3 percentage, and decomposition temperature

Surface modification processes	structure damage	[O]/[C] (%)	sp^2 (%)	I_D/I_G	TGA decomposition temperature $({}^{\circ}C)$
No treatment	N.A.	11.2	48.8	0.89	600
Strong acid treatment only	Severe	$46.2 \sim 52.7$ (Max. for $9 h$)	$22.6 \sim 27.5$ (Max. for $9 h$)	0.96	$635 - 638$ (Min. for $6h$)
Dilute acid treatment for 2 h only	Light	24.8 릴		0.91	684
Ion treatment only	Light	$11.1 - 59.8$ (Max. at $H_2/O_2 = 25/25$	$27.1 - 44.2$ (Max. at $H_2/O_2=10/40$ F	$0.91 \sim 1.27$ (Max. at $H_2/O_2 = 40/10$	$594 \sim 599$ (Min. at $H_2/O_2 = 40/10$
Two-step process	Light	$19.5 \sim 52.4$ (Max. at $H_2/O_2 = 25/25$	$33.4 - 59.5$ \blacksquare (Max. at $H_2/O_2 = 50/0$	$0.95 \sim 1.26$ (Max. at $H_2/O_2 = 25/25$	$651 - 684$ (Min. at $H_2/O_2 = 50/10$

3. For the two-step process combining the 5 min ion pretreatment and a post dilute nitric acid treatment, the results show that the ion-treated MWCNTs at medium H_2/O_2 ratio (= 25/25 (sccm/sccm)) can be further treated by dilute acid to increase the decomposition temperature from \sim 595 °C up to 684 °C without sacrificing the functionalization $([O]/[C]=52.4\%)$. By comparing different process methods, both nitric/sulfuric and dilute acid treatments can enhance decomposition temperature by eliminating the impurities and the smaller CNTs to vary the size distribution of the tubes but it causes either too much structure damage or too long treating time. According to the results, the two-step process is relatively simple and efficient to functionalize CNTs, simultaneously enhance the decomposition temperature and cause no significant structure damage.

Chapter 6

Future Prospects

In this study, both the ion treatment, and the two-step process combining the ion pretreatment and a 0.25 M HNO₃ acid treatment are shown to be effective processes for surface modification of MWCNTs. The resulting nanotubes by the present ion treatment can be with very high polar functional groups and with insignificant structure and morphology changes while the process time is only with 20 min. When the MWCNTs are treated by the present two-step process, the nanotubes can be with high polar functional groups, high thermal stability, and high structural integrity. However, some subjects should be further studied:

- (a) The functionalized CNTs by the present processes are further used for some specific applications, such as solar cell technologies, biosensors, drug and vaccine delivery vehicles, and novel biomaterials.
- (b) In order to evaluate the effects of the present processes on various CNTs and graphene, different CNTs, graphene, and CNTs produced by various processes are to be functionalized by these two processes.
- (c) Other process conditions including working pressure, positive bias voltage, and working distance between plasma zone and specimen are further studied because these conditions strongly correlate with the functionalization efficiency.
- (d) According to the results, the thermal stability strongly correlates with the defects and the diameter of the nanotubes. It is important to find a method to measure the diameter distribution of the CNTs.

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